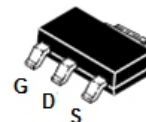


ACMS04N06Y-HF

N-Channel
RoHS Device
Halogen Free



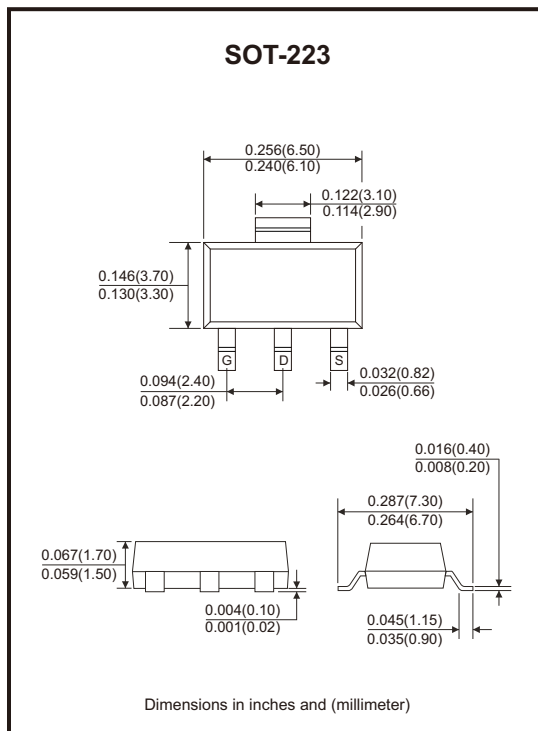
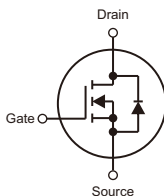
Features

- Low on resistance.
- Low on threshold voltage.
- Fast switching speed.
- Low gate drive.
- AEC-Q101 Qualified.

Mechanical data

- Case: SOT-223, molded plastic.
- Molding compound: UL flammability classification rating 94V-0.
- Terminals: Matte tin plated, solderable per MIL-STD-202, method 208.

Circuit Diagram



Maximum Ratings (at TA=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V _{DSS}	60	V
Gate-source voltage	V _{GSS}	±20	V
Continuous drain current	I _D	4	A
Pulsed drain current	I _{DM}	20	A
Power dissipation (Note 1)	P _D	3.1	W
Thermal resistance junction to air (Note 1)	R _{θJA}	40.3	°C/W
Operating junction temperature range	T _J	-55 to +150	°C
Storage temperature range	T _{STG}	-55 to +150	°C

Notes: 1. When surface mounted to an FR4 board using minimum recommended pad size.

Electrical Characteristics (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	60			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 60\text{V}, V_{GS} = 0\text{V}$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$			± 100	nA
On Characteristics						
Static drain-source on-resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}, I_D = 4\text{A}$		75	105	m Ω
		$V_{GS} = 4.5\text{V}, I_D = 4\text{A}$		78	125	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.8	1	2	V
Forward transconductance	g_{fs}	$V_{DS} = 15\text{V}, I_D = 4\text{A}$		4.9		S
Dynamic Characteristics						
Input capacitance	C_{iss}	$V_{GS} = 0\text{V}, V_{DS} = 40\text{V}, f = 1\text{MHz}$		530		pF
Output capacitance	C_{oss}			27		
Reverse transfer capacitance	C_{rss}			17		
Switching Characteristics						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 30\text{V}, V_{GS} = 10\text{V}, R_G = 6\Omega, I_D = 4\text{A}$		1.95		ns
Turn-on rise time	t_r			3.5		
Turn-off delay time	$t_{d(off)}$			8.2		
Turn-off fall time	t_f			4.6		
Total gate charge	Q_g	$V_{DD} = 30\text{V}, I_D = 4\text{A}, V_{GS} = 10\text{V}$		15.5		nC
Gate to source charge	Q_{gs}			1.6		
Gate to drain (miller) charge	Q_{gd}			1.7		
Source-Drain Diode Characteristics						
Diode forward voltage	V_{SD}	$I_{SD} = 4\text{A}, V_{GS} = 0\text{V}$		1	2	V

Rating and Characteristic Curves (ACMS04N06Y-HF)

Fig.1 - On-Region Characteristics

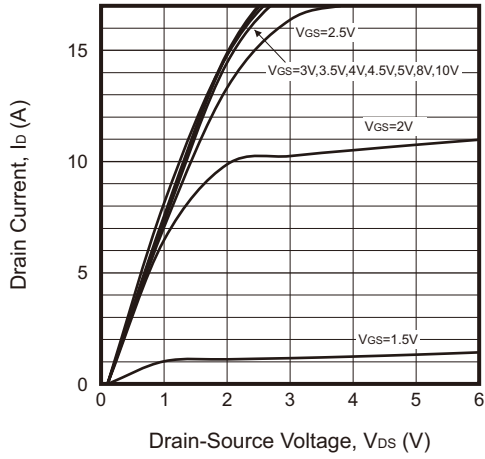


Fig.2 - On-Resistance vs. Drain Current and Gate Voltage

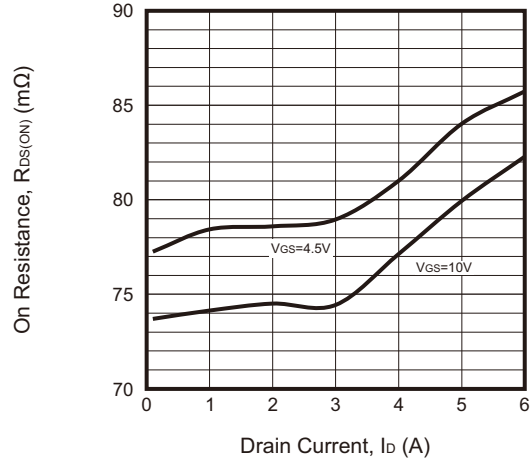


Fig.3 - On-Resistance vs. Gate-Source Voltage

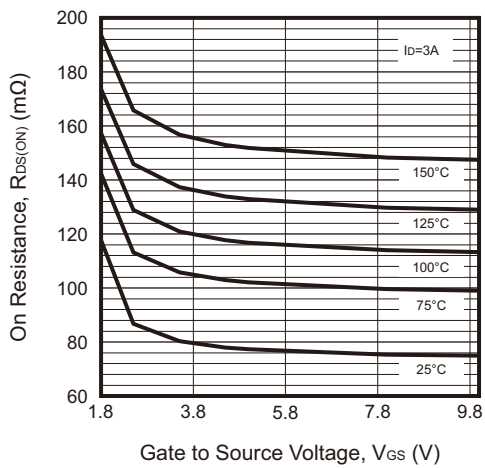


Fig.4 - Body-Diode Characteristics

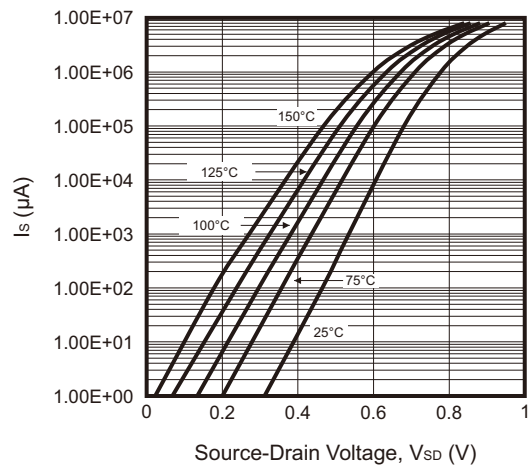


Fig.5 - On-Resistance vs. Junction Temperature

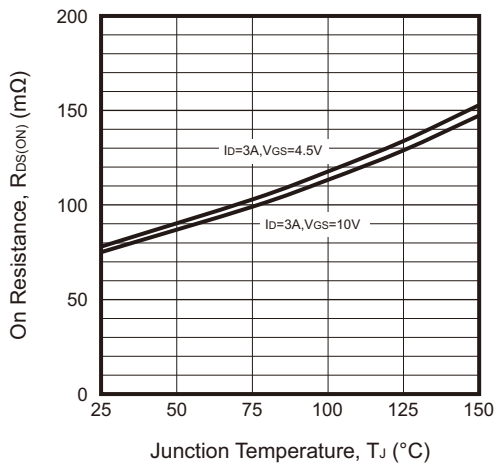
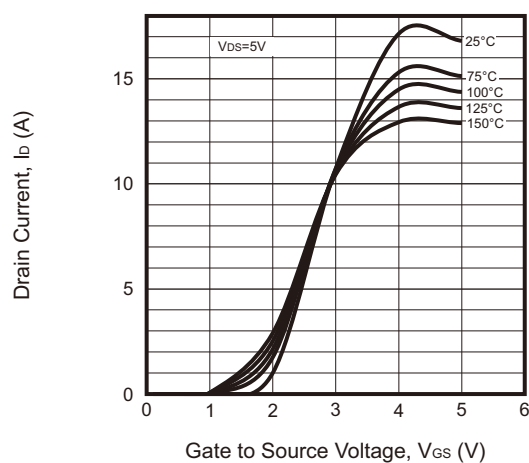


Fig.6 - Transfer Characteristics



Rating and Characteristic Curves (ACMS04N06Y-HF)

Fig.7 - Capacitance Characteristics

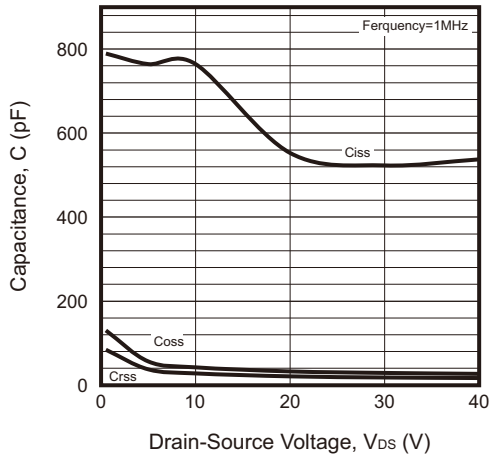


Fig.8 - Gate-Voltage vs. Junction Temperature

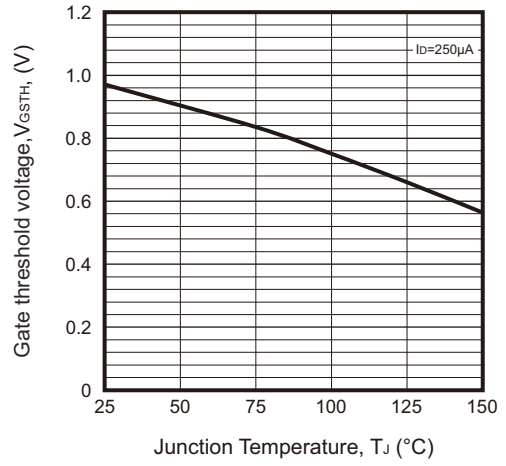
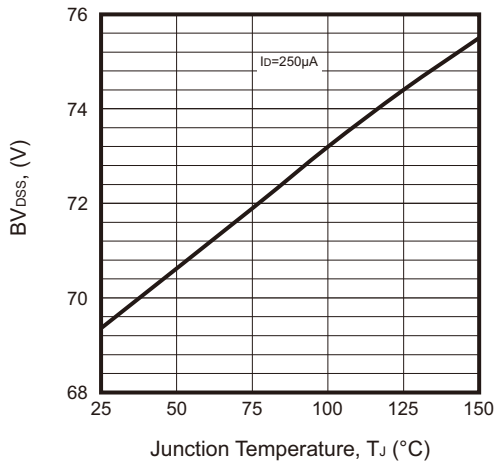
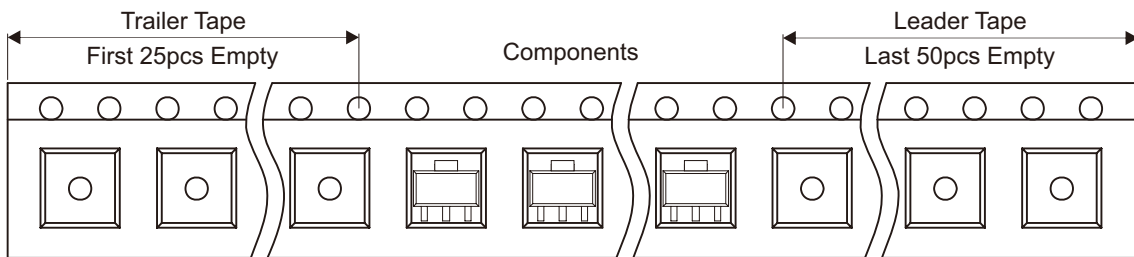
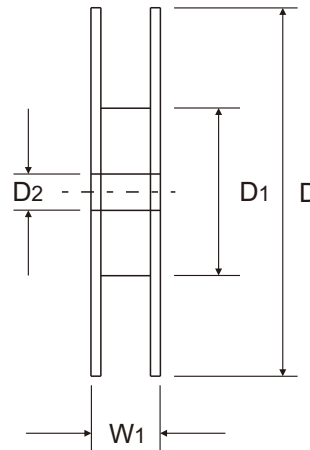
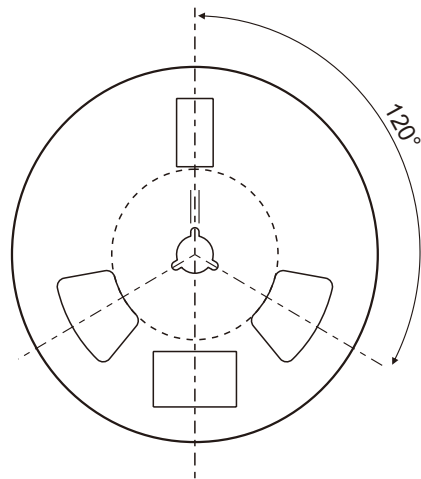
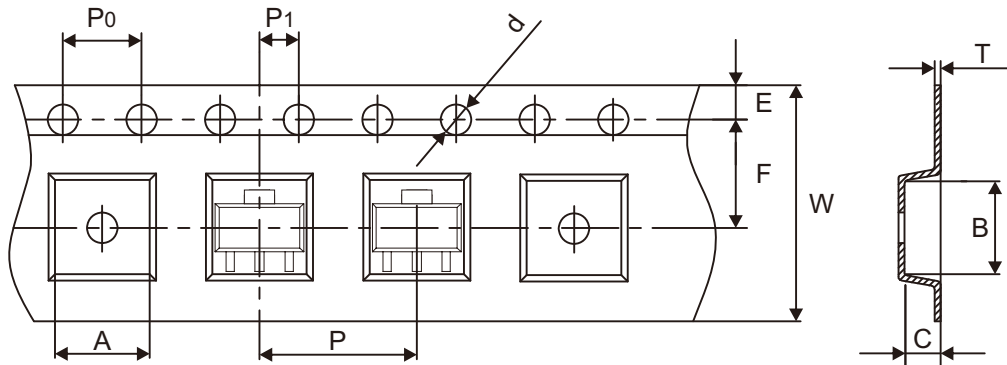


Fig.9 - Drain-Source vs. Junction Temperature



Reel Taping Specification

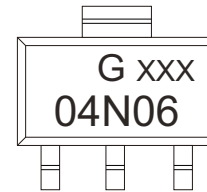


SOT-223	SYMBOL	A	B	C	d	D	D ₁	D ₂
	(mm)	7.05 ± 0.10	7.40 ± 0.10	1.90 ± 0.10	1.55 ± 0.05	330.00 ± 2.00	100.00 ± 2.00	13.00 ± 0.20
	(inch)	0.278 ± 0.004	0.291 ± 0.004	0.075 ± 0.004	0.061 ± 0.002	12.992 ± 0.079	3.937 ± 0.079	0.512 ± 0.008

SOT-223	SYMBOL	E	F	P	P ₀	P ₁	T	W	W ₁
	(mm)	1.75 ± 0.10	5.50 ± 0.10	8.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	0.25 ± 0.05	12.00 + 0.30 - 0.10	18.50 ± 2.00
	(inch)	0.069 ± 0.004	0.217 ± 0.004	0.315 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.010 ± 0.002	0.472 + 0.012 - 0.004	0.728 ± 0.079

Marking Code

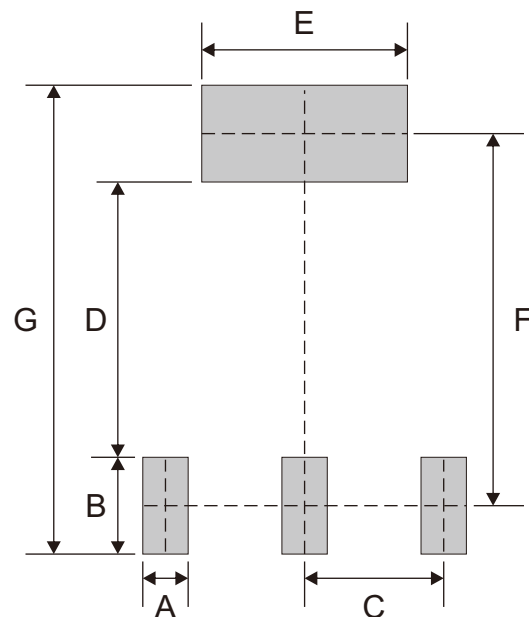
Part Number	Marking Code
ACMS04N06Y-HF	04N06



XXX = Control code

Suggested P.C.B. PAD Layout

SIZE	SOT-223	
	(mm)	(inch)
A	0.75	0.030
B	1.60	0.063
C	2.30	0.091
D	4.55	0.179
E	3.40	0.134
F	6.15	0.242
G	7.75	0.305



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-223	4,000	13